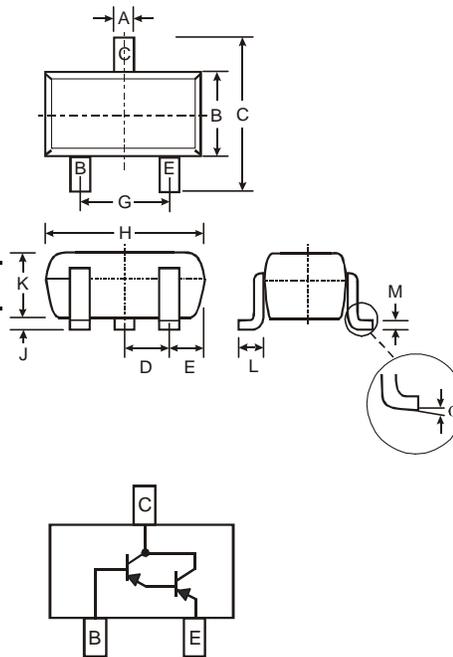


Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (MMSTA13/MMSTA14)
- Ultra-Small Surface Mount Package
- Ideal for Medium Power Amplification and Switching
- High Current Gain
- **Lead Free/RoHS Compliant (Note 2)**
- **"Green" Device (Note 3 and 4)**



SOT-323		
Dim	Min	Max
A	0.25	0.40
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
E	0.30	0.40
G	1.20	1.40
H	1.80	2.20
J	0.0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.18
α	0°	8°
All Dimensions in mm		

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- MMSTA63 Marking K2E, K3E, See Page 3
- MMSTA64 Marking K3E, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

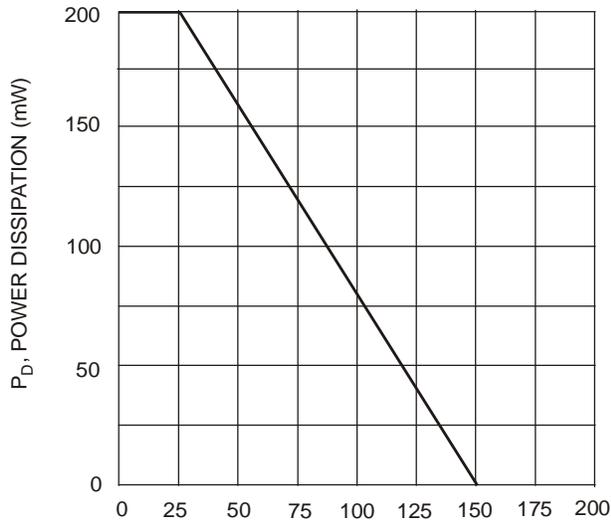
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-30	V
Collector-Emitter Voltage	V_{CEO}	-30	V
Emitter-Base Voltage	V_{EBO}	-10	V
Collector Current - Continuous	I_C	-500	mA
Power Dissipation (Note 1)	P_d	200	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	625	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 2. No purposefully added lead.
 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php
 4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

Electrical Characteristics @T_A = 25°C unless otherwise specified

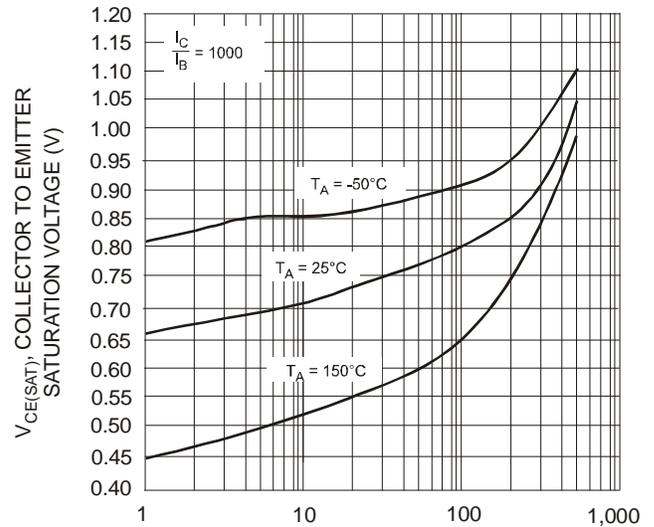
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-30	—	V	I _C = -100μA, V _{BE} = 0V
Collector Cutoff Current	I _{CBO}	—	-100	nA	V _{CB} = -30V, I _E = 0
Emitter Cutoff Current	I _{EBO}	—	-100	nA	V _{EB} = -10V, I _C = 0
ON CHARACTERISTICS (Note 5)					
DC Current Gain	MMSTA63 MMSTA64 MMSTA63 MMSTA64	h _{FE}	5,000 10,000 10,000 20,000	—	I _C = -10mA, V _{CE} = -5.0V I _C = -10mA, V _{CE} = -5.0V I _C = -100mA, V _{CE} = -5.0V I _C = -100mA, V _{CE} = -5.0V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	-1.5	V	I _C = -100mA, I _B = -100μA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	-2.0	V	I _C = -100mA, V _{CE} = -5.0V
SMALL SIGNAL CHARACTERISTICS					
Current Gain-Bandwidth Product	f _T	125	—	MHz	V _{CE} = -5.0V, I _C = -10mA, f = 100MHz

Notes: 5. Short duration pulse test used to minimize self-heating effect.



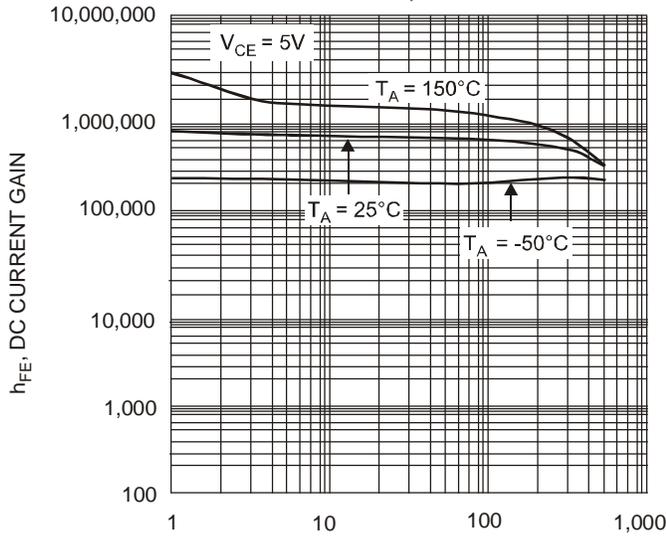
T_A, AMBIENT TEMPERATURE (°C)

Fig. 1, Max Power Dissipation vs. Ambient Temperature



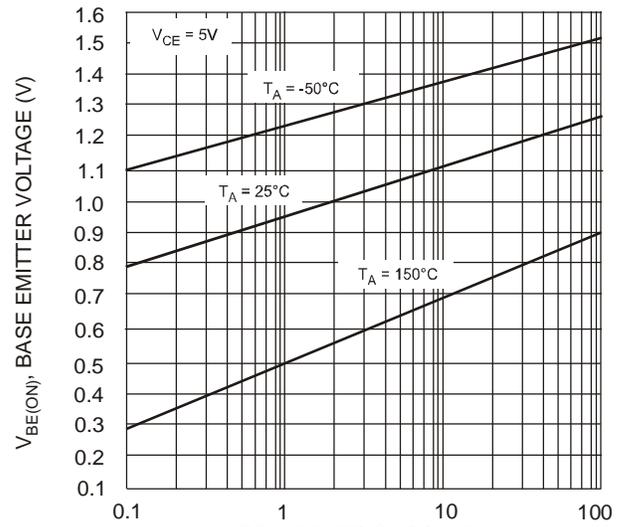
I_C, COLLECTOR CURRENT (mA)

Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current



I_C, COLLECTOR CURRENT (mA)

Fig. 3, DC Current Gain vs. Collector Current



I_C, COLLECTOR CURRENT (mA)

Fig. 4, Base Emitter Voltage vs. Collector Current

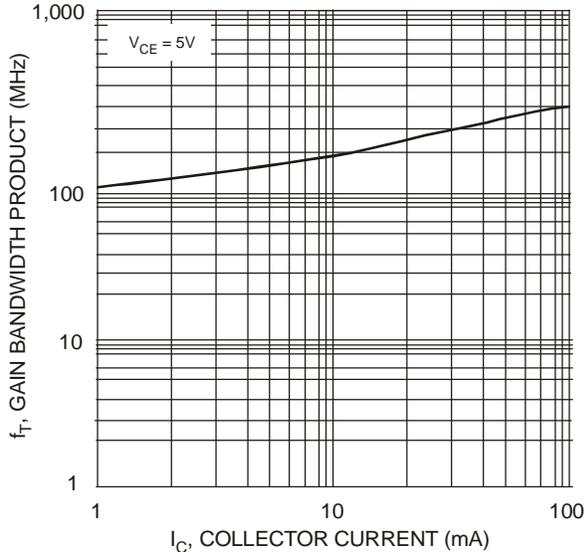


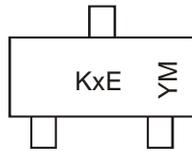
Fig. 5, Gain Bandwidth Product vs. Collector Current

Ordering Information (Note 4 & 6)

Device	Packaging	Shipping
MMSTA63-7-F	SOT-323	3000/Tape & Reel
MMSTA64-7-F	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



KxE = Product Type Marking Code, e.g. K2E = MMSTA63
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	M	N	P	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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